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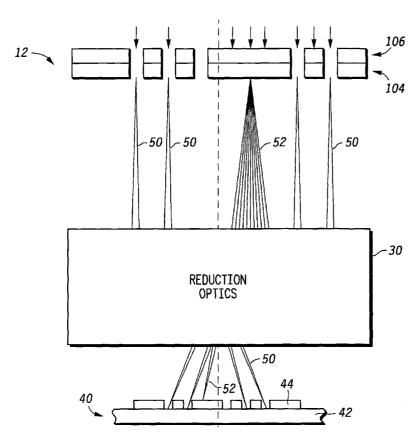
- (71) Applicant: MOTOROLA, INC. [US/US]; 1303 East Algonquin Road, Schaumburg, IL 60196 (US).
- (72) Inventors: MANGAT, Pawitter; 3688 East Encinas Avenue, Gilbert, AZ 85234 (US). MOGAB, Joe; 22 Ehrlich Road, Austin, TX 78746 (US). SMITH, Kenneth,

H.; 1331 West Bartlett Way, Chandler, AZ 85248 (US). WASSON, James, R.; 2960 East Brooks Street, Gilbert, AZ 85296 (US).

- (74) Agents: KOCH, William, E. et al.; Corporate Law Department, Intellectual Property Section, 7700 West Parmer Lane, MD: TX32/PL02, Austin, TX 78729 (US).
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(54) Title: METHOD FOR FABRICATING A THIN-MEMBRANE STENCIL MASK AND METHOD FOR MAKING A SEMI-CONDUCTOR DEVICE USING THE SAME



(57) Abstract: A stencil mask (12 or 12) has both a thin membrane layer (106) and a stress controlled layer (104) for enabling electron and ion projection lithography at very small The thin membrane geometries. layer (106) is within a range of substantially forty to two hundred nanometers and is preferably silicon nitride, and the stress controlled layer is preferably a metal or a metal alloy. Annealing of the stress controlled layer (104) may be performed to obtain a desired stress characteristic. Semiconductors are made using the mask by projecting radiation through the thin membrane stencil mask and reduction optics (30) onto resist (44) formed on a plurality of die, the radiation forming a contrast image on the resist that is subsequently developed. Commercially available lithography equipment is compatible with the thin stencil mask.

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According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

 $\begin{array}{ccc} \text{Minimum documentation searched (classification system followed by classification symbols)} \\ IPC & 7 & GO3F \end{array}$

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

EPO-Internal, PAJ, INSPEC

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Further documents are listed in the continuation of box C.	χ Patent family members are listed in annex.
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Name and mailing address of the ISA European Patent Office, P.B. 5818 Patentlaan 2 NL – 2280 HV Rijswijk	Authorized officer
Tel. (+31-70) 340-2040, Tx. 31 651 epo nl, Fax: (+31-70) 340-3016	Heywood, C

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